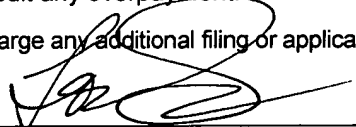




AF

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AMENDMENT TRANSMITTAL LETTER				Docket No. M4065.0278/P278	
Application No. 09/653,281	Filing Date August 31, 2000	Examiner Richard A. Booth	Art Unit 2812		
Applicant(s): Kevin L. Beaman, et al.					
Invention: USE OF ATOMIC OXIDATION FOR FABRICATION OF OXIDE-NITRIDE-OXIDE STACK FOR FLASH MEMORY DEVICES					
TO THE COMMISSIONER FOR PATENTS					
Transmitted herewith is an amendment in the above-identified application. The fee has been calculated and is transmitted as shown below.					
CLAIMS AS AMENDED					
	Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate	
Total Claims	33	- 45 =	0	x	0.00
Independent Claims	3	- 3 =	0	x	0.00
Multiple Dependent Claims (check if applicable) <input type="checkbox"/>					
Other fee (please specify):					
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT:					0.00
<input checked="" type="checkbox"/> Large Entity <input type="checkbox"/> Small Entity					
<input checked="" type="checkbox"/> No additional fee is required for this amendment.					
<input type="checkbox"/> Please charge Deposit Account No. _____ in the amount of \$ _____. A duplicate copy of this sheet is enclosed.					
<input type="checkbox"/> A check in the amount of \$ _____ to cover the filing fee is enclosed.					
<input type="checkbox"/> Payment by credit card. Form PTO-2038 is attached.					
<input checked="" type="checkbox"/> The Commissioner is hereby authorized to charge and credit Deposit Account No. <u>04-1073</u> as described below. A duplicate copy of this sheet is enclosed.					
<input checked="" type="checkbox"/> Credit any overpayment.					
<input checked="" type="checkbox"/> Charge any additional filing or application processing fees required under 37 CFR 1.16 and 1.17.					
 Thomas J. D'Amico Attorney Reg. No.: 28,371 DICKSTEIN SHAPIRO MORIN & OSHINSKY LLP 2101 L Street NW Washington, DC 20037-1526 (202) 828-2232				Dated: <u>November 18, 2005</u>	



Docket No.: M4065.0278/P278
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Kevin L. Beaman, et al.

Examiner: Richard A. Booth

Application No.: 09/653,281

Art Unit: 2812

Filed: August 31, 2000

For: USE OF ATOMIC OXIDATION FOR
FABRICATING OF OXIDE-NITRIDE-OXIDE
STACK FOR FLASH MEMORY DEVICES

AMENDMENT IN RESPONSE TO A FINAL OFFICE ACTION

Commissioner for Patents
MS: Amendment
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

This paper is in response to the final Office Action dated October 24, 2005.
Please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins
on page 2 of this paper.

Remarks begin on page 8 of this paper.